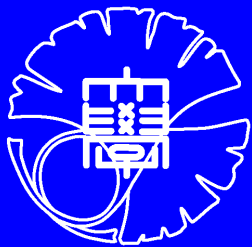


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# On-chip di/dt Detector Circuit for Power Supply Line

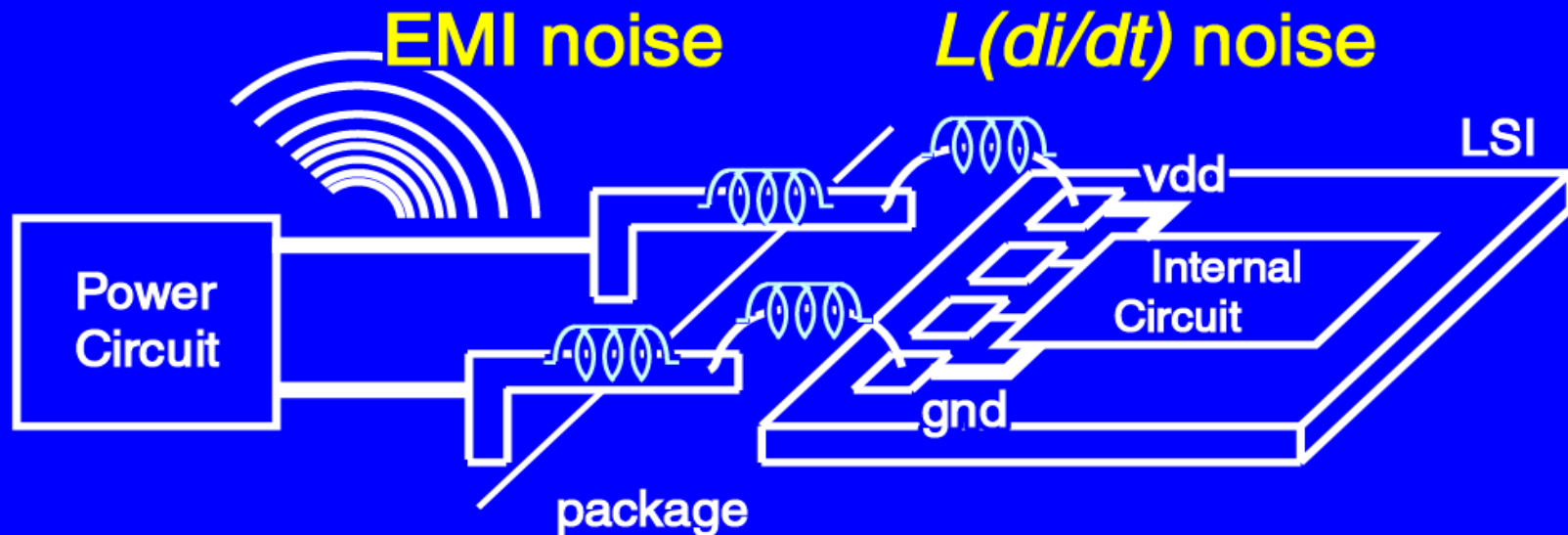
Toru Nakura<sup>#</sup>, Makoto Ikeda<sup>\*</sup>, Kunihiro Asada<sup>\*</sup>



*<sup>#</sup>Dept. of Electronic Engineering,  
<sup>\*</sup>VLSI Design and Education Center,  
University of Tokyo, Tokyo, Japan*

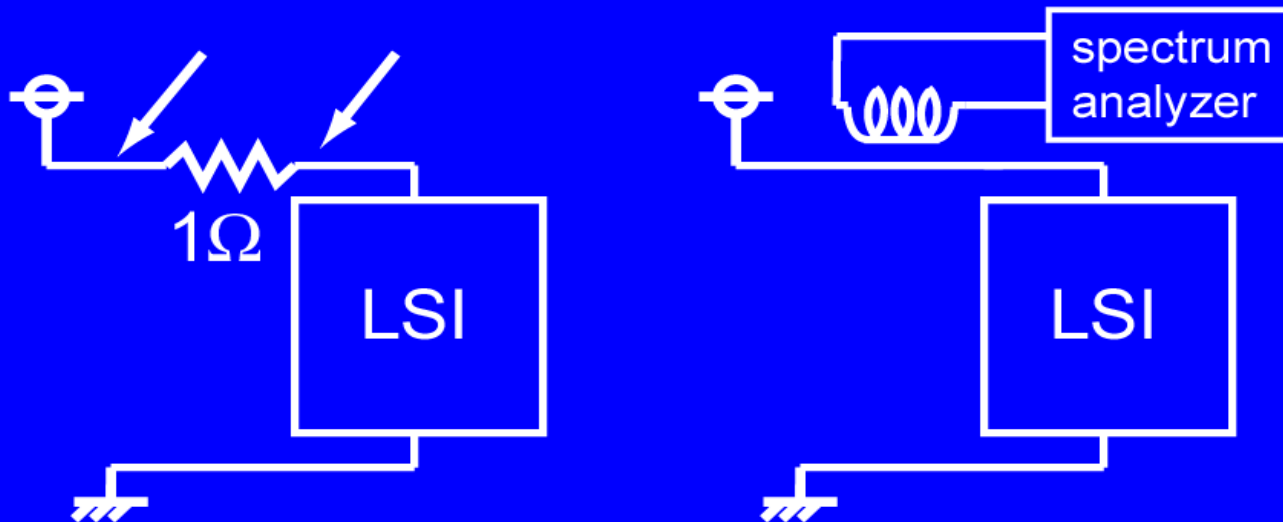
# Background

- $di/dt$  is becoming a critical issue
  - $L(di/dt)$  noise of low voltage LSIs
  - EMI noise of high-speed operation LSIs
- Need to measure the  $di/dt$



# Conventional Current Meas.

- Probe the voltage difference of the R
  - Needs numerical calculation
- Probe the magnetic field by pickup coil
  - Phase information is lost



# Contents

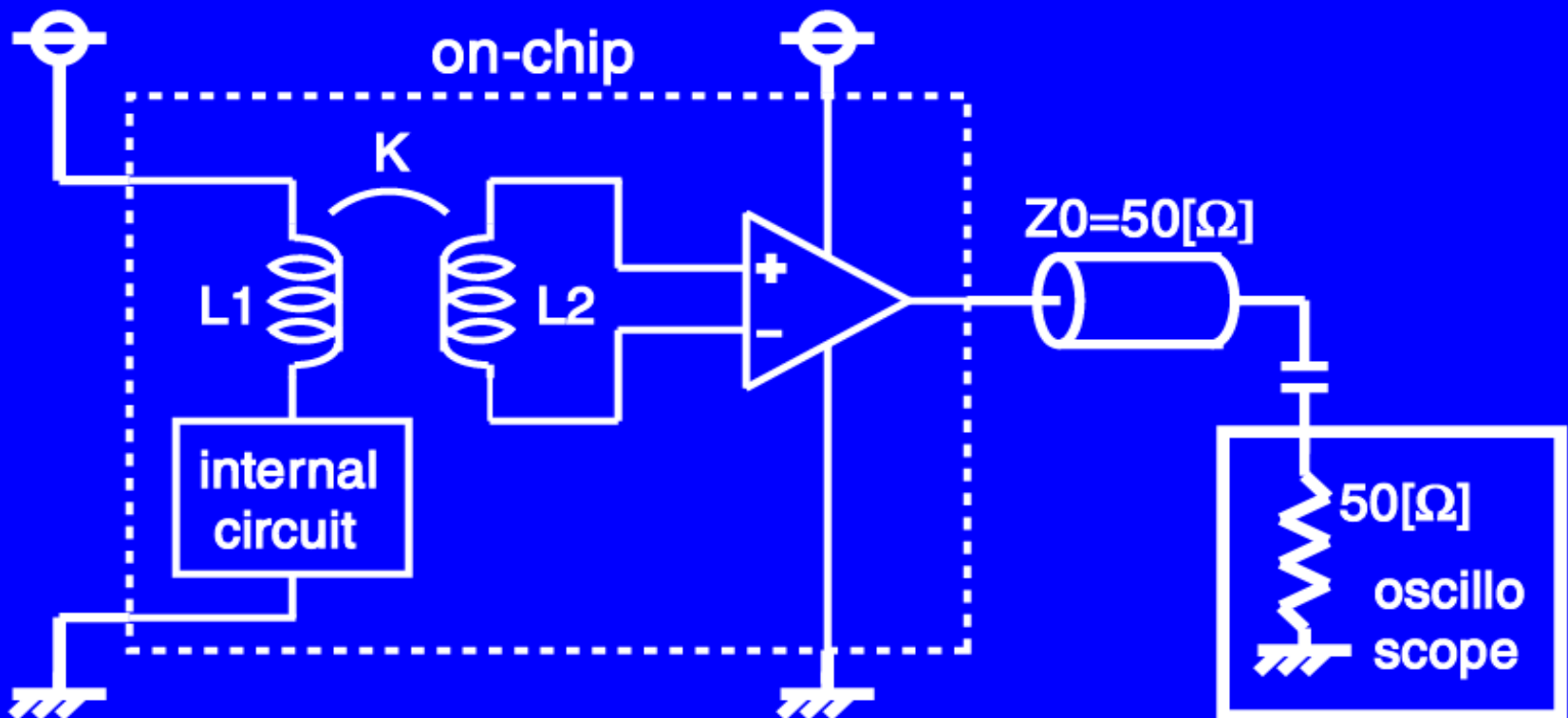
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- **Introduction of our di/dt detector circuit**
  - Mutual Inductor
  - Amplifier
  - Setup for measurement
- **Simulation Waveforms**
- **Summary**

# Block Diagram

- L2 picks up the  $di/dt$ , induce the voltage
- Amplifier amplifies/output the voltage



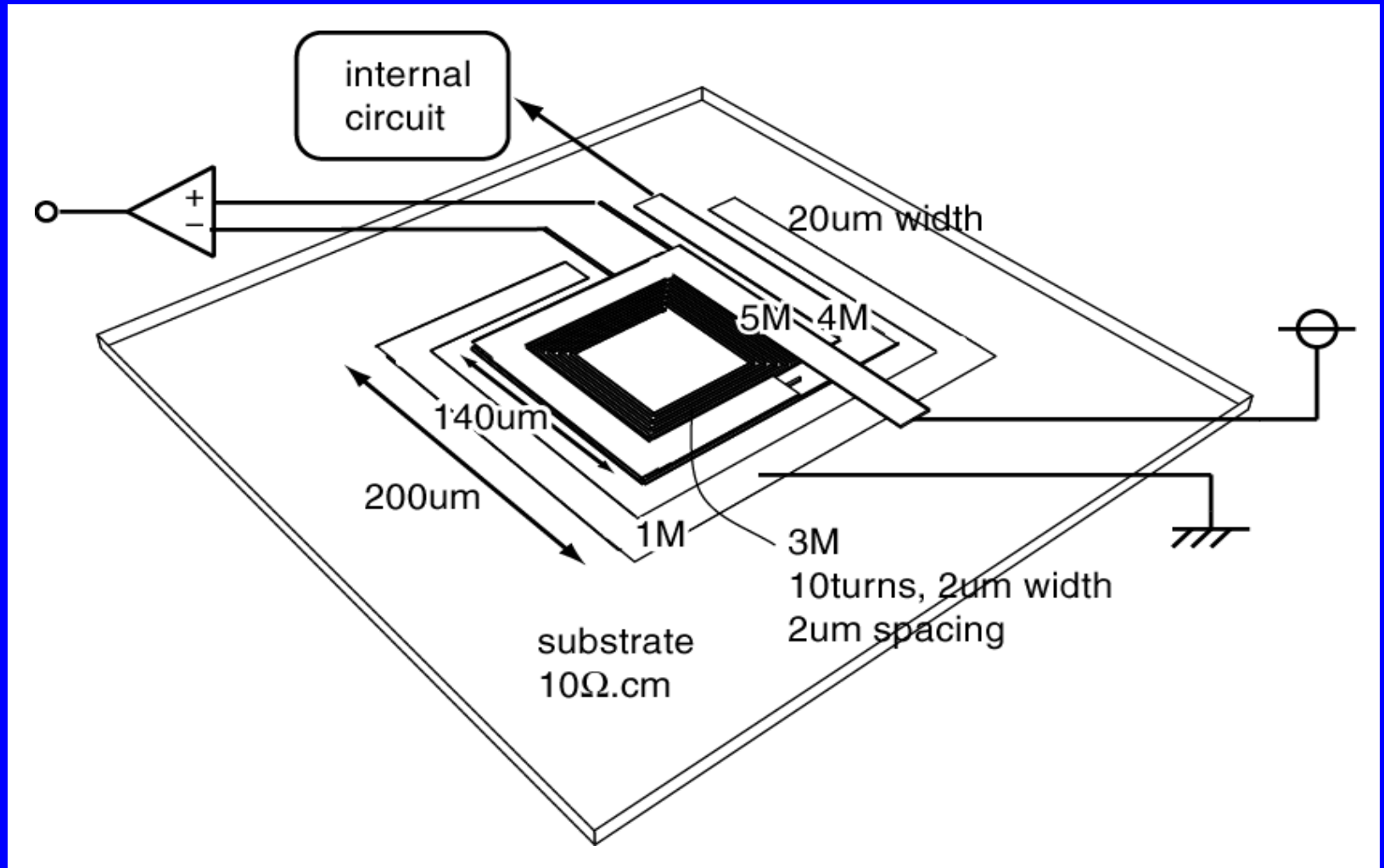
# Advantage

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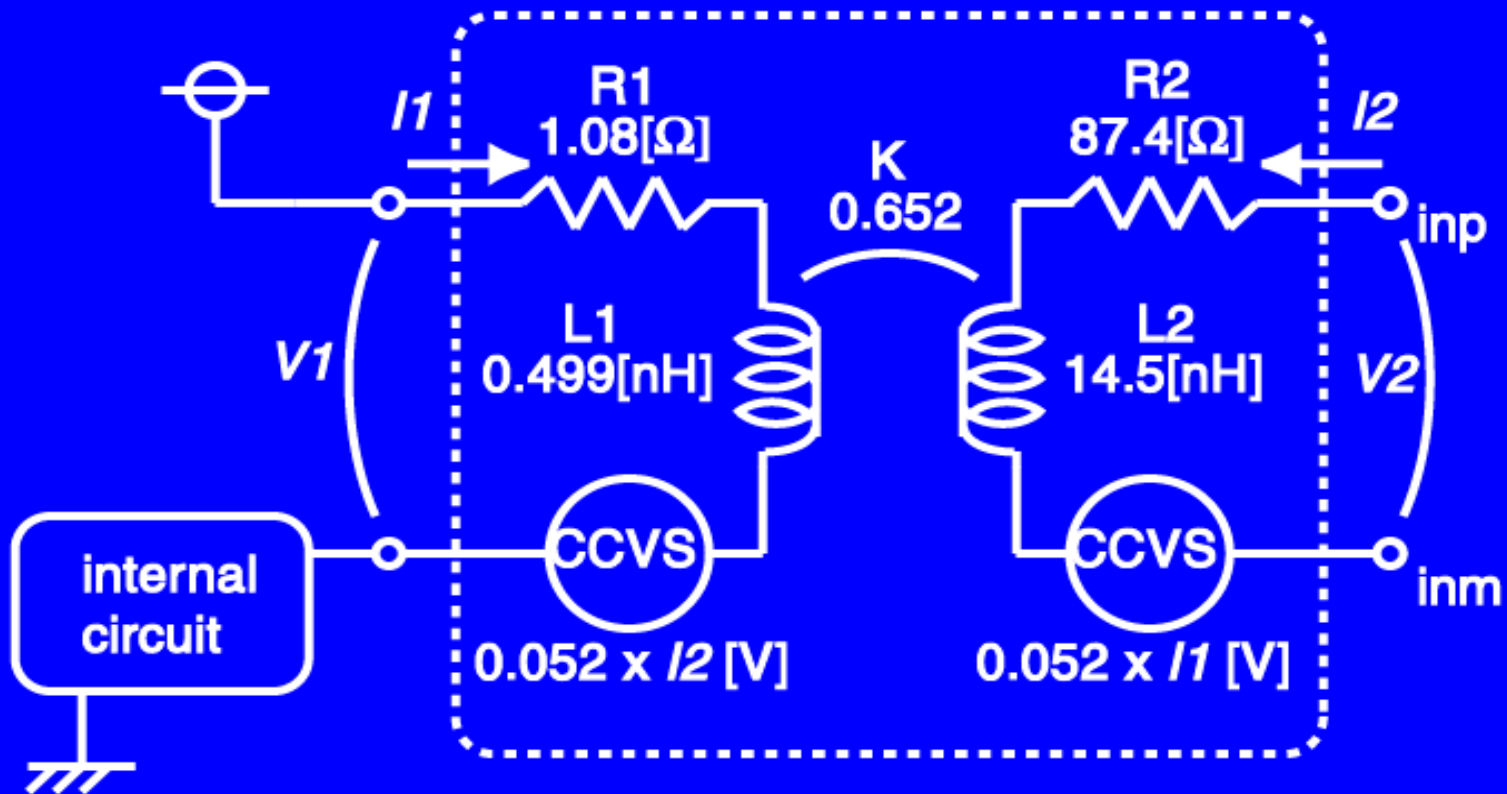
- **On-chip**
- **di/dt waveform without numerical calculation**
- **Real time**
- **Feedback di/dt control is possible**

# Mutual Inductor



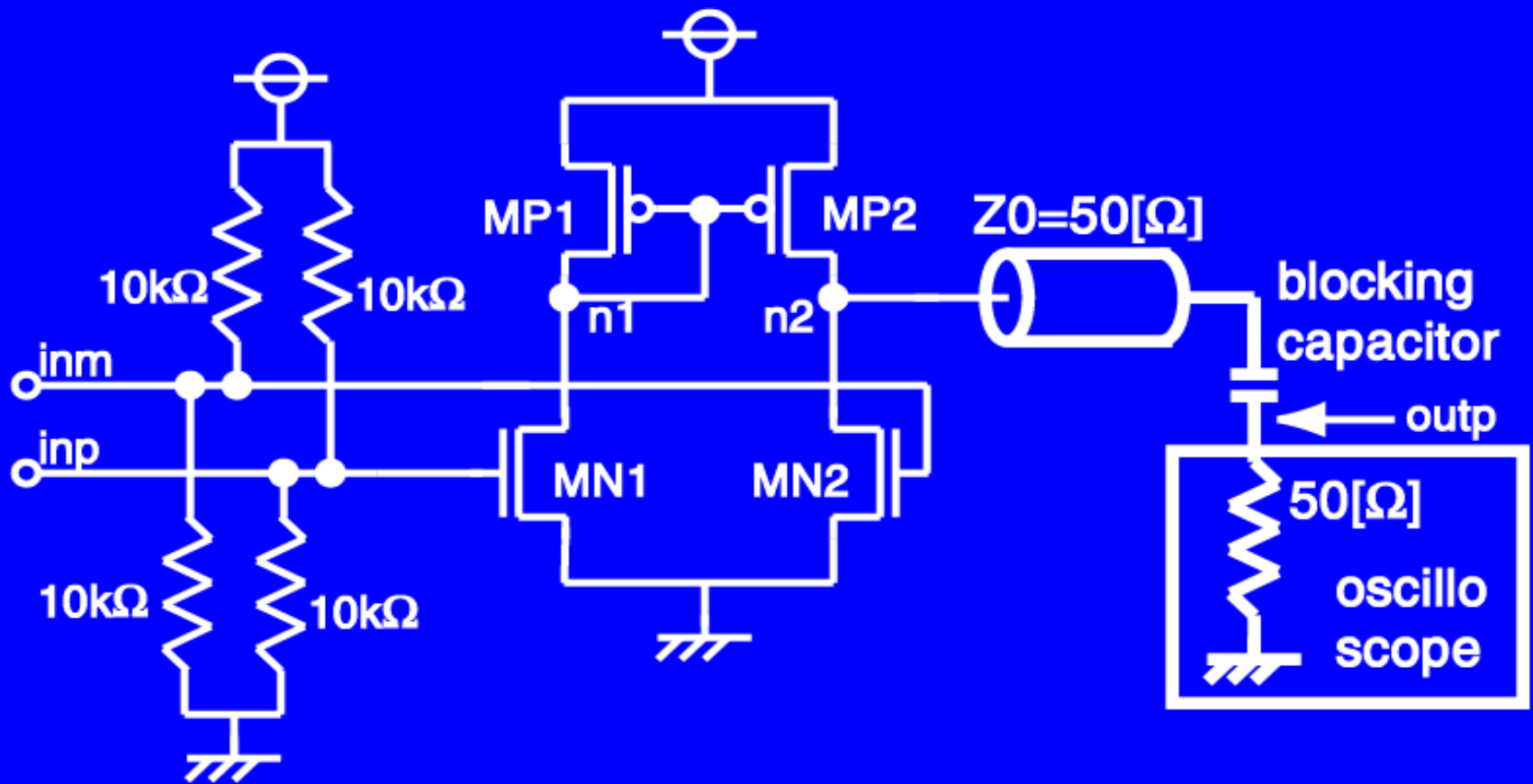
# Equivalent Circuit

- Extracted by FastHenry



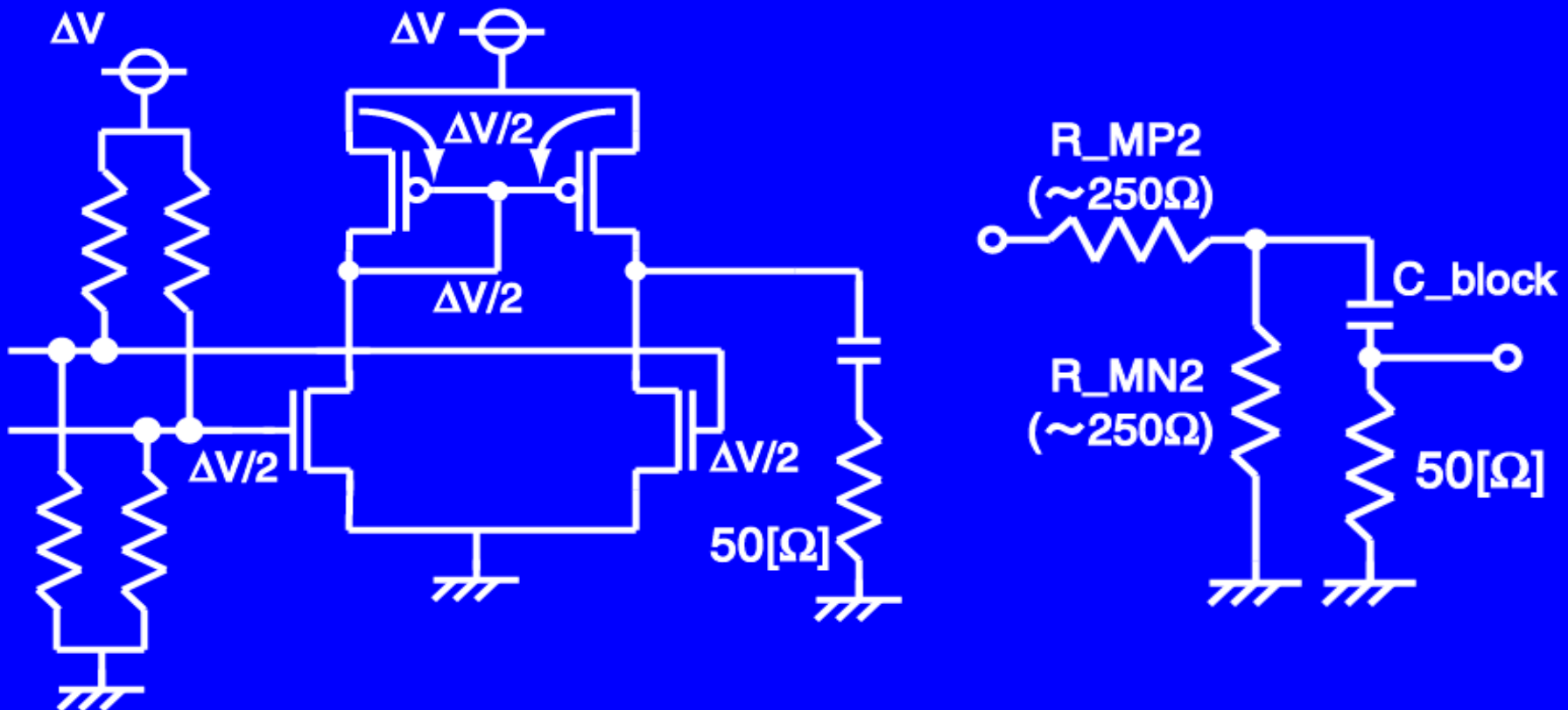


# Amplifier/Output buffer



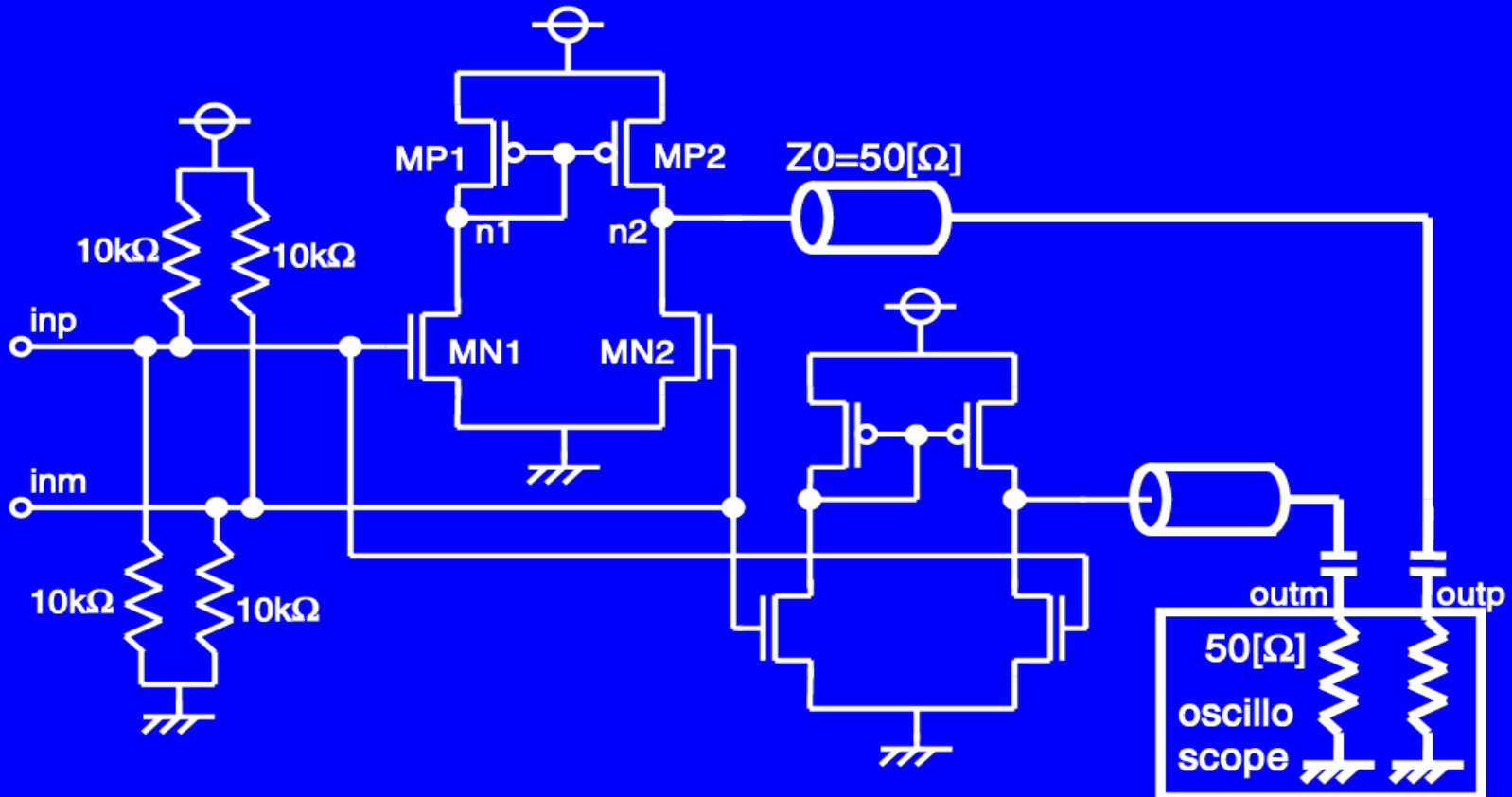
# Noise Tolerance

- Common mode noise is eliminated
- Vdd noise is suppressed to 14% (by 86%)



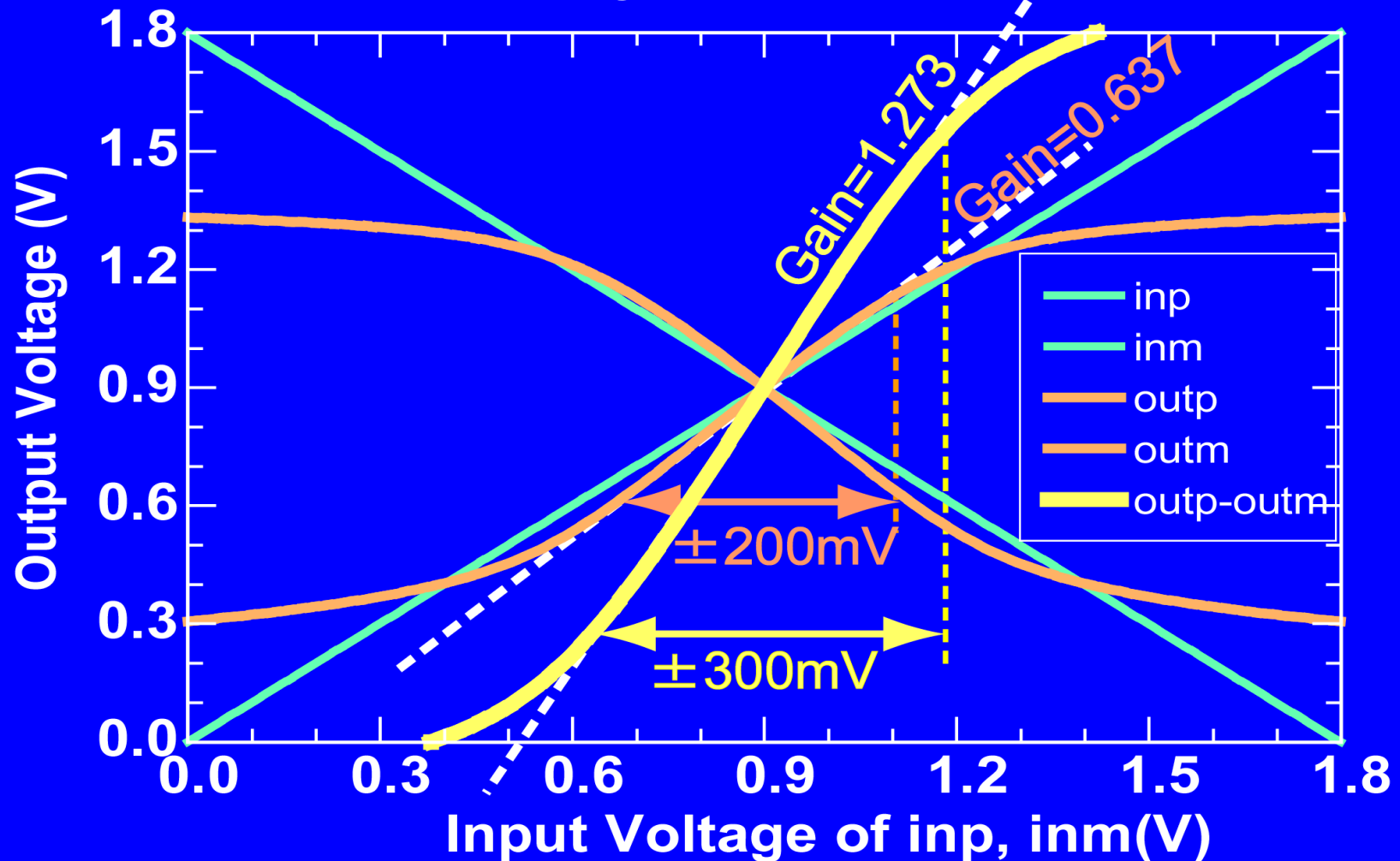
# Single or Dual?

- Noise immunity, Sensitivity, Symmetric
- Require two pins, numerical calculation



# Linearity of the Amplifier

- Cut-off frequency is over 10GHz



# Sensitivity

- $L_1=0.499\text{nH}$ ,  $L_2=14.5\text{nH}$ ,  $K=0.652$ ,  $G=1.273$

$$V_{inp} - V_{inm} = K\sqrt{L_1L_2} \frac{dl_1}{dt} \quad I = 1\sin 2\pi 1e9t \rightarrow$$

$$dl/dt = 2\pi 1e9 \cos 2\pi ft$$

$$V_{out} = G(V_{inp} - V_{inm})$$

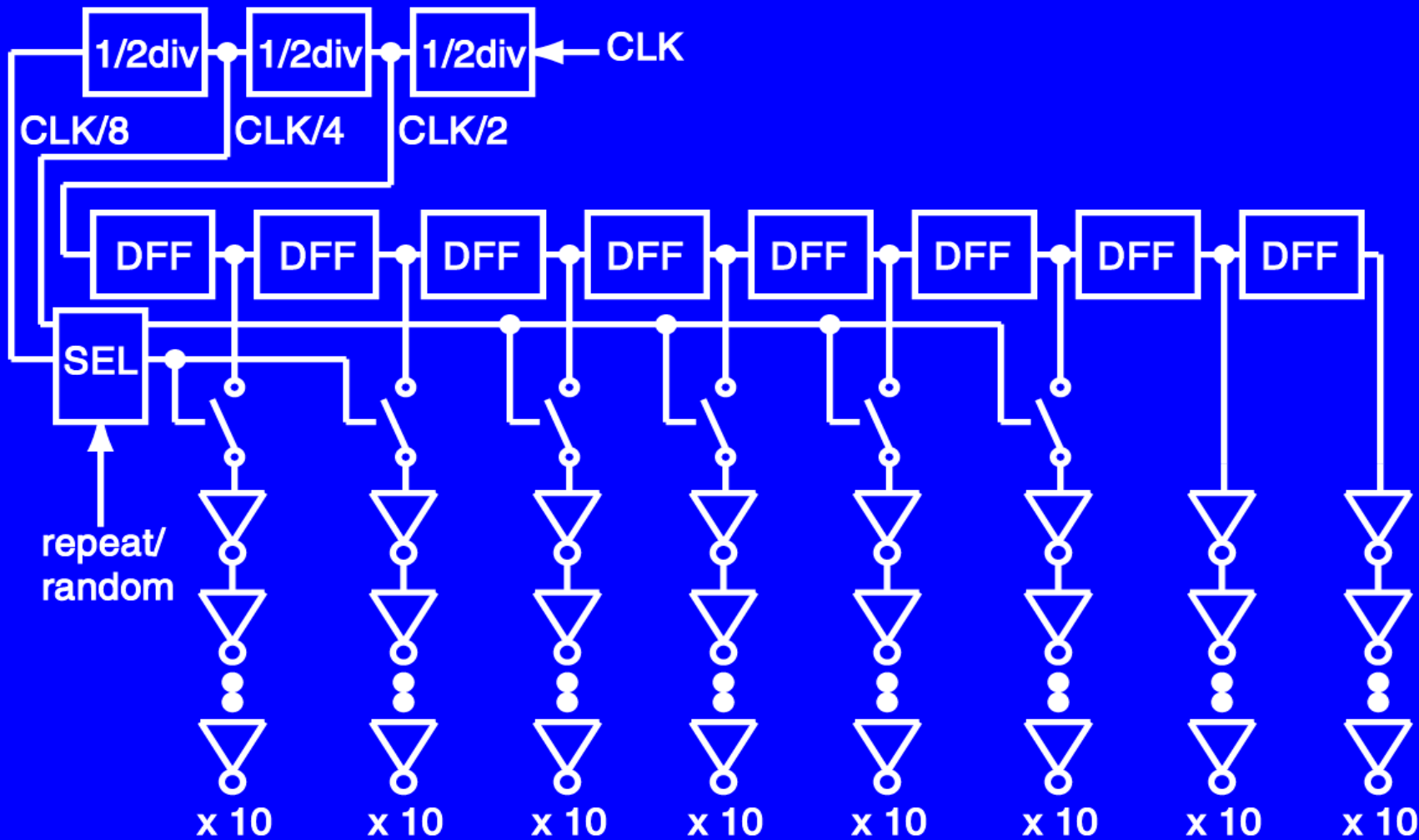
$$V_{out} = GK\sqrt{L_1L_2} \frac{dl_1}{dt} = A_{didt2vout} \frac{dl_1}{dt} = 2.23 \times 10^{-9} \frac{dl_1}{dt}$$

$$\frac{dl_1}{dt} = \frac{1}{A_{didt2vout}} V_{out} = 4.48 \times 10^8 V_{out}$$

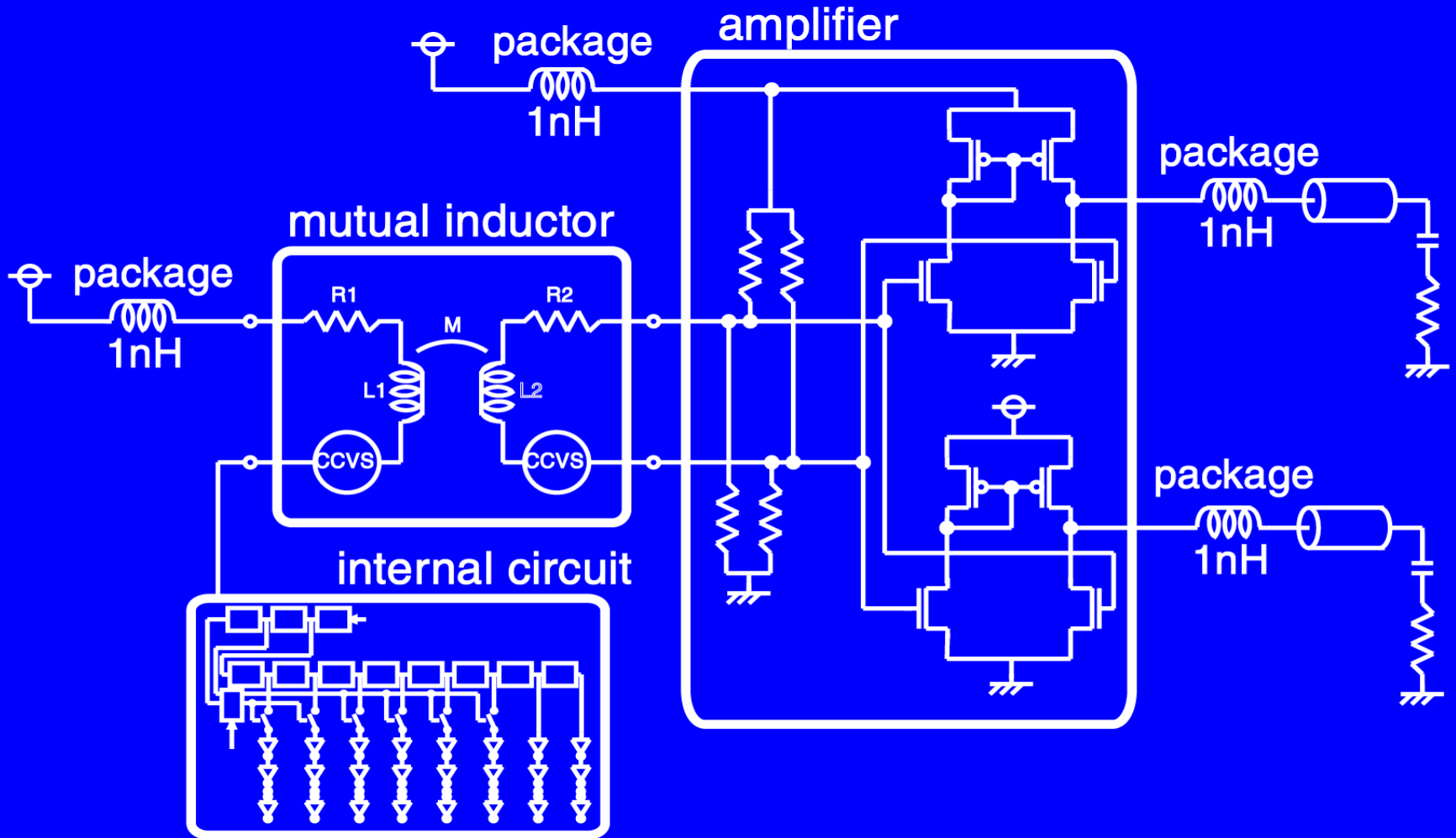
$$\frac{dl_1}{dt}_{lim} = \pm \frac{1}{K\sqrt{L_1L_2}} V_{amp\_in\_lin} = \pm 1.71 \times 10^8 \text{ [A/s]}$$

$$\frac{dl_1}{dt}_{res} = \frac{1}{A_{didt2vout}} V_{out\_res} = 4.48 \times 10^6 \text{ [A/s]} \quad (V_{out\_res} = 10\text{mV})$$

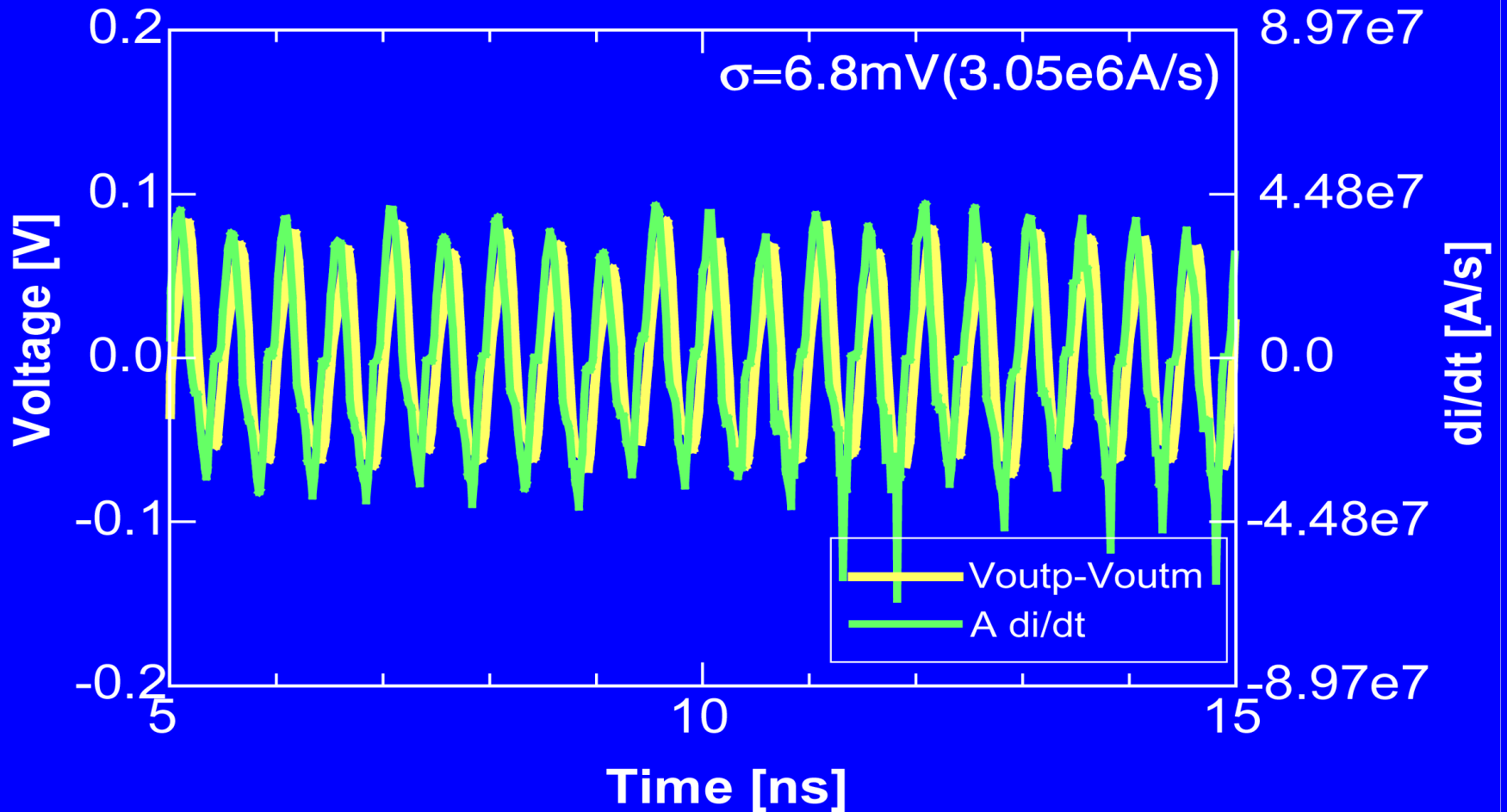
# Test Circuit



# Whole Test Circuit

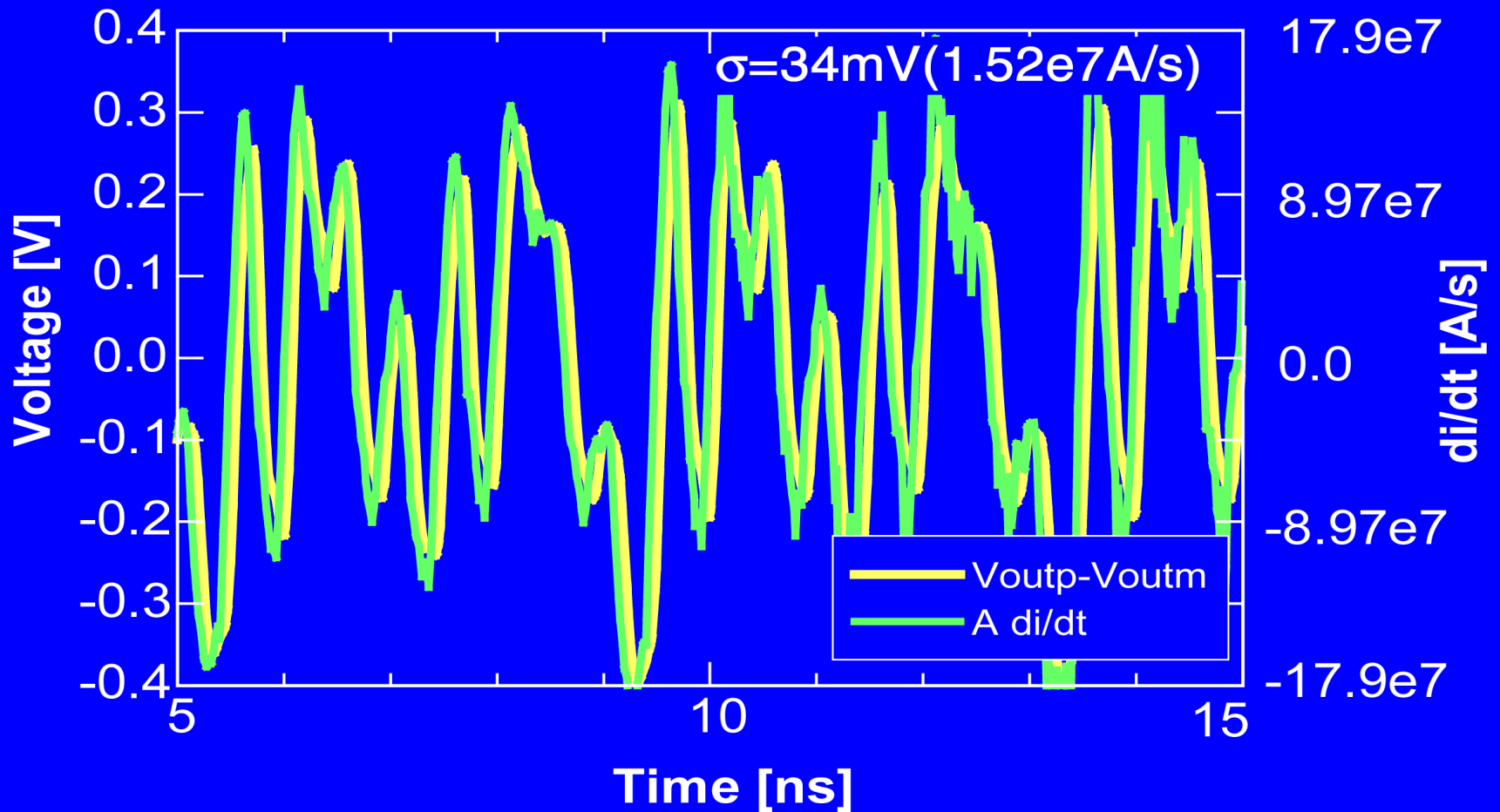


# di/dt Waveform (repeat)

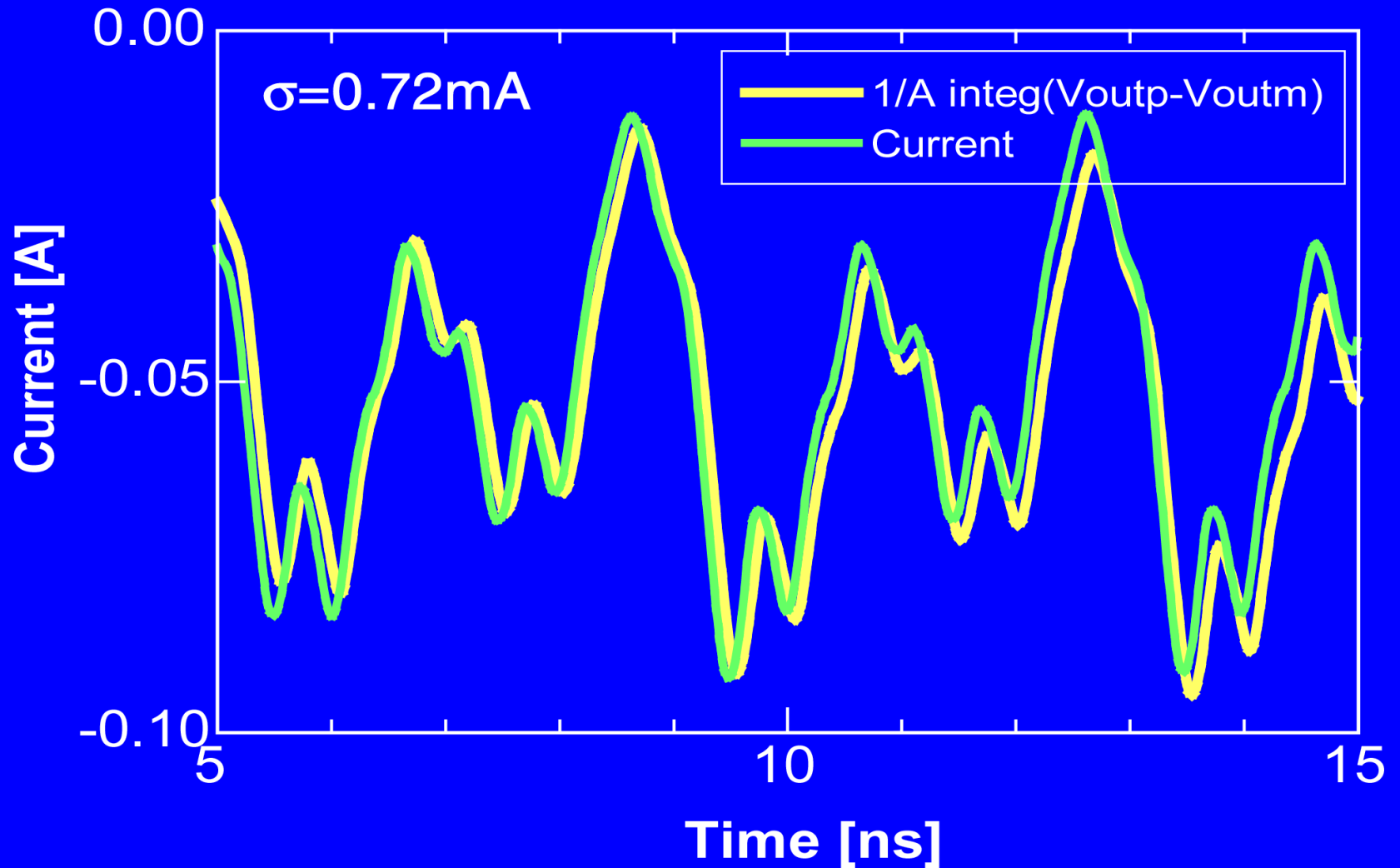




# di/dt Waveform (random)



# Current Waveforms



# Summary

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- **An on-chip di/dt detector is proposed.**
- **It consists of a spiral inductor and an amplifier.**
- **The accuracy is  $1.52 \times 10^7$  A/s by an HSPICE simulation (random case).**
- **Current waveform can be obtained by integration of the di/dt output, with the accuracy of 0.72mA.**

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# Q&A